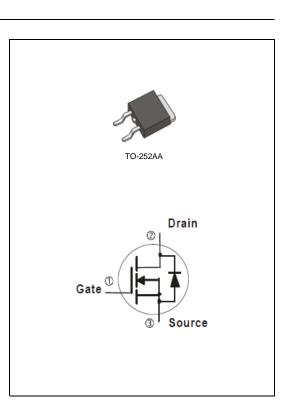
ΡΛΝ	JIT
	SEMI
	CONDUCTOR

PJD11N06A-AU 60V N-Channel Enhancement Mode MOSFET Voltage 60 V Current 11 A Features • R_{DS(ON)}, V_{GS}@10V, I_D@6A<75mΩ</td> • R_{DS(ON)}, V_{GS}@4.5V, I_D@3A<90mΩ</td> • High switching speed • Improved dv/dt capability • Low Gate Charge • Low reverse transfer capacitance • AEC-Q101 qualified

- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : TO-252AA Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0104 ounces, 0.297grams



Maximum Ratings and Thermal Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETE	R	SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	60	v	
Gate-Source Voltage		V_{GS}	<u>+</u> 20	V	
Continuous Drain Current (Note 4)	T _C =25°C		11	A	
	T _c =100°C	I _D	7		
Pulsed Drain Current (Note 1)	T _C =25°C	I _{DM}	44		
Power Dissipation	T _c =25°C	Po	30	W	
	T _C =100°C		15		
Continuous Drain Current (Note 4)	T _A =25°C	I _D	3.7	А	
	T _A =70°C		2.9		
Power Dissipation	T _A =25°C	PD	2.4	w	
	T _A =70°C		1.6		
Single Pulse Avalanche Energy	lote 6)	E _{AS}	25	mJ	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~175	°C	
Typical Thermal Resistance (Note 4,5)	Junction to Case	$R_{ extsf{ heta}JC}$	5	°C/W	
	Junction to Ambient	$R_{ extsf{ heta}JA}$	62.5		

• Limited only By Maximum Junction Temperature



PJD11N06A-AU

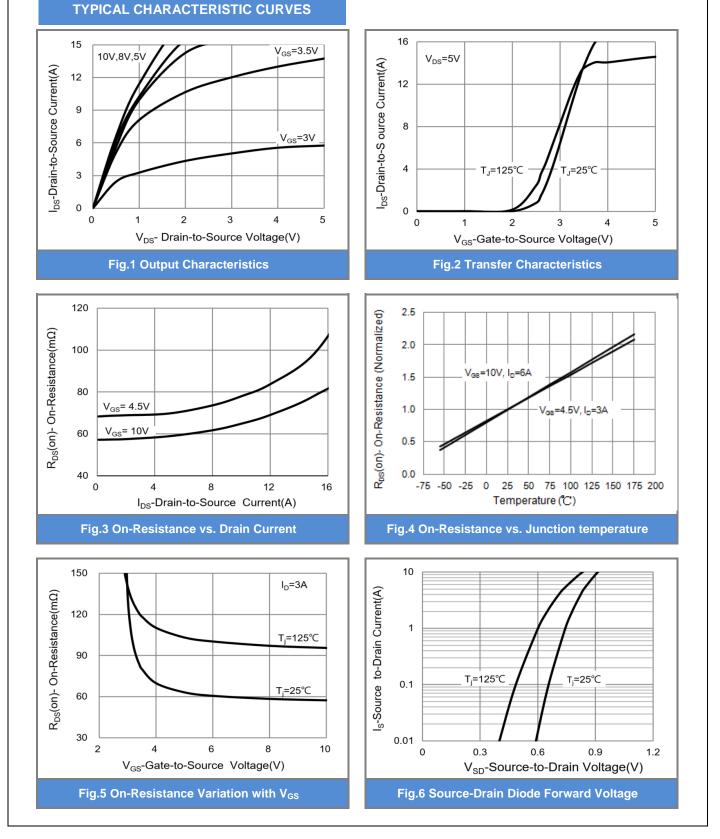
Electrical Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	60	-	-	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250$ uA	1	1.8	2.5	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =6A	-	53	75	mΩ
		V _{GS} =4.5V, I _D =3A	-	61	90	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 6)						
Total Gate Charge	Qg	V_{DS} =48V, I _D =6A, V_{GS} =10V ^(Note 1,2)	-	9.3	-	nC
Gate-Source Charge	Q _{gs}		-	2.2	-	
Gate-Drain Charge	Q _{gd}		-	1.9	-	
Input Capacitance	Ciss	V _{DS} =15V, V _{GS} =0V, f=1MHZ	-	509	-	pF
Output Capacitance	Coss		-	47	-	
Reverse Transfer Capacitance	Crss		-	23	-	
Turn-On Delay Time	td _(on)	V_{DD} =30V, I_{D} =1A, V_{GS} =10V, R_{G} =3.3 Ω ^(Note 1,2)	-	3.2	-	
Turn-On Rise Time	tr		-	9.7	-	ns
Turn-Off Delay Time	td _(off)		-	18.5	-	
Turn-Off Fall Time	t _f	κ _G =3.3Ω	-	6.4	-	
Drain-Source Diode						
Maximum Continuous Drain-Source					44	A
Diode Forward Current	I _S		-	-	11	
Diode Forward Voltage	V _{SD}	I _S =1A, V _{GS} =0V	-	0.75	1	V

NOTES :

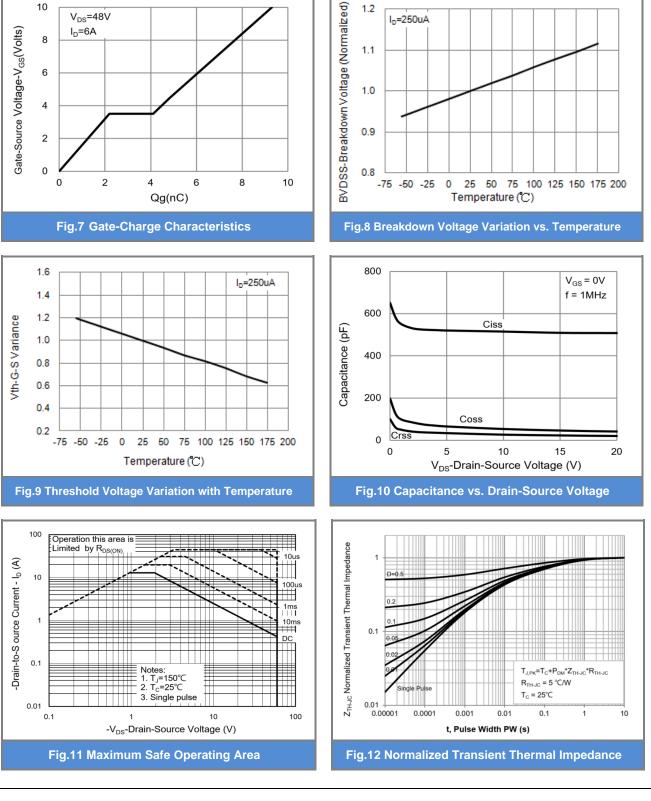
- 1. Pulse width
- 2. Essentially independent of operating temperature typical characteristics.
- Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.

March 28,2019-REV.00



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1.2

1.1

Ip=250uA

TYPICAL CHARACTERISTIC CURVES

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PANJ SFMI CONDUCTOR

10

8

V_{DS}=48V

I_D=6A



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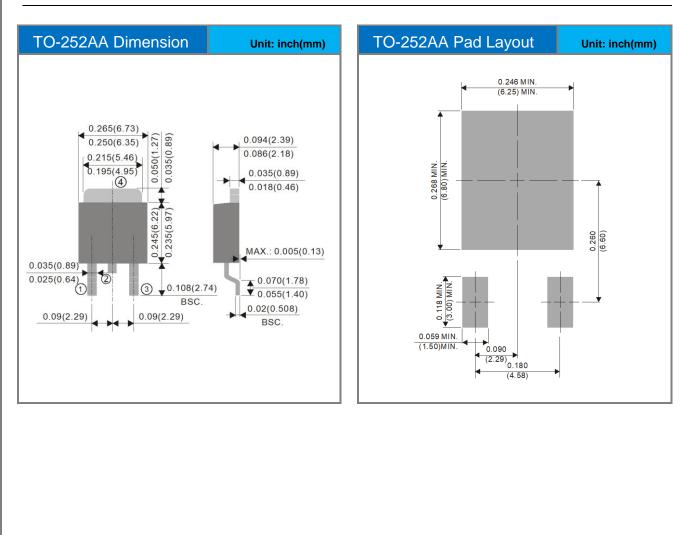


PJD11N06A-AU

Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJD11N06A-AU_L2_000A1	TO-252AA	3,000pcs / 13" reel	D11N06A	Halogen free

Packaging Information & Mounting Pad Layout





PJD11N06A-AU

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